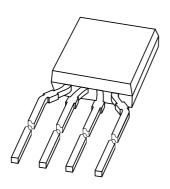
# **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# **KMZ10A**Magnetic field sensor

Product specification Supersedes data of 1996 Nov 08 File under Discrete Semiconductors, SC17 1998 Mar 24





# Magnetic field sensor

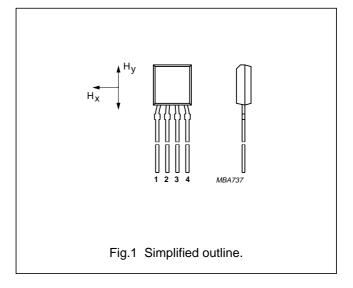
## KMZ10A

#### **DESCRIPTION**

The KMZ10A is an extremely sensitive magnetic field sensor, employing the magnetoresistive effect of thin-film permalloy. Its properties enable this sensor to be used in a wide range of applications for navigation, current and field measurement, revolution counters, angular or linear position measurement and proximity detectors, etc.

#### **PINNING**

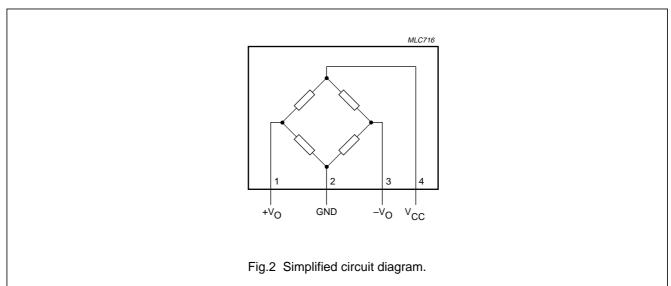
PIN	SYMBOL	DESCRIPTION
1	+V <sub>O</sub>	output voltage
2	GND	ground
3	$-V_{O}$	output voltage
4	$V_{CC}$	supply voltage



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
V <sub>CC</sub>	bridge supply voltage	_	5	_	V
T <sub>bridge</sub>	bridge operating temperature	-40	_	+150	°C
H <sub>y</sub>	magnetic field strength	-0.5	_	+0.5	kA/m
H <sub>x</sub>	auxiliary field	_	0.5	_	kA/m
S	S sensitivity		16	_	$\frac{mV/V}{kA/m}$
R <sub>bridge</sub>	bridge resistance	0.8	_	1.6	kΩ
V <sub>offset</sub>	offset voltage	-1.5	_	+1.5	mV/V

#### **CIRCUIT DIAGRAM**



# Magnetic field sensor

KMZ10A

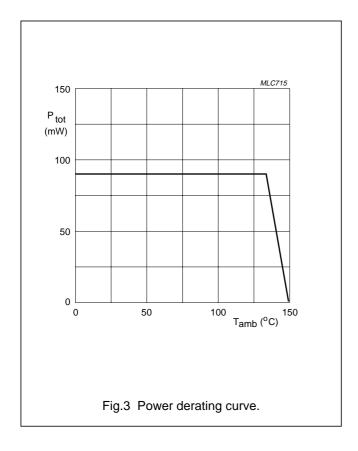
#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CC</sub>	bridge supply voltage		_	9	V
P <sub>tot</sub>	total power dissipation	up to T <sub>amb</sub> = 134 °C	_	90	mW
T <sub>stg</sub>	storage temperature	note 1	-65	+150	°C
T <sub>bridge</sub>	bridge operating temperature		-40	+150	°C

#### Note

1. Maximum operating temperature of the thin-film permalloy.



# Magnetic field sensor

KMZ10A

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT	
R <sub>th j-a</sub>	thermal resistance from junction to ambient	180	K/W	

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C;  $H_x$  = 0.5 kA/m; notes 1 and 2;  $V_{CC}$  = 5 V unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
H <sub>y</sub>	magnetic field strength	note 2	-0.5	_	+0.5	kA/m
S	sensitivity	notes 2 and 3	13	-	19	$\frac{mV/V}{kA/m}$
TCV <sub>O</sub>	temperature coefficient of output voltage	$V_{CC} = 5 \text{ V};$ $T_{amb} = -25 \text{ to } +125 ^{\circ}\text{C}$	_	-0.4	-	%/K
		$I_{CC} = 3 \text{ mA};$ $T_{amb} = -25 \text{ to } +125 ^{\circ}\text{C}$	_	-0.15	_	%/K
R <sub>bridge</sub>	bridge resistance		0.8	_	1.6	kΩ
TCR <sub>bridge</sub>	temperature coefficient of bridge resistance	$T_{bridge} = -25 \text{ to } +125 ^{\circ}\text{C}$	_	0.25	_	%/K
V <sub>offset</sub>	offset voltage		-1.5	_	+1.5	mV/V
TCV <sub>offset</sub>	offset voltage drift	$T_{bridge} = -25 \text{ to } +125 ^{\circ}\text{C}$	-6	_	+6	<u>μV/V</u> Κ
FL	linearity deviation of output	$H_y = 0 \text{ to } \pm 0.25 \text{ kA/m}$	_	_	0.8	%·FS
	voltage	$H_y = 0 \text{ to } \pm 0.4 \text{ kA/m}$	_	_	2.5	%·FS
		$H_y = 0 \text{ to } \pm 0.5 \text{ kA/m}$	_	-	4.0	%·FS
FH	hysteresis of output voltage		_	_	0.5	%·FS
f	operating frequency		0	_	1	MHz

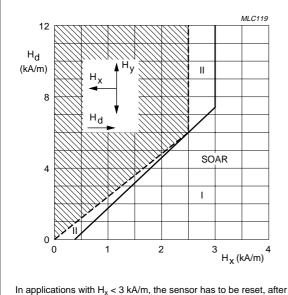
#### Notes

- 1. Before first operation or after operation outside the SOAR (Fig.4) the sensor has to be reset by application of an auxiliary field  $H_x = 3 \text{ kA/m}$ .
- 2. No disturbing field  $(H_d)$  allowed; for stable operation under disturbing conditions see Fig.4 (SOAR) and see Fig.5 for decrease of sensitivity.

$$\label{eq:S} 3. \quad S \, = \, \frac{(\,V_{\,O} \,\, at \,\, H_{\,y} = 0.4 \,\, kA/m) \, - \, (\,V_{\,O} \,\, at \,\, H_{\,y} = 0)}{0.4 \times V_{\,CC}} \; .$$

# Magnetic field sensor

KMZ10A

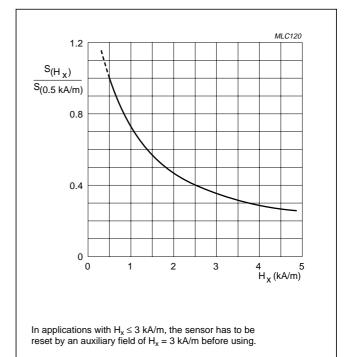


leaving the SOAR, by an auxiliary field of  $H_x = 3 \text{ kA/m}$ .

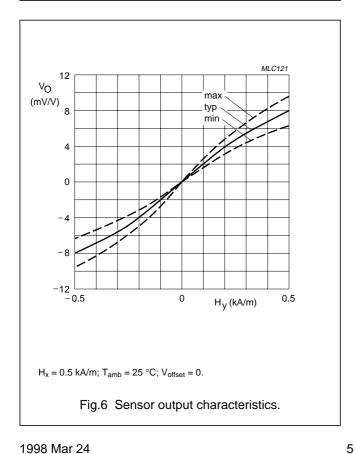
I = Region of permissible operation.

II = Permissible extension if  $H_y < 0.15$  A/m.

Safe Operating Area (permissible disturbing field  $H_d$  as a component of auxiliary field  $H_x$ ).



Relative sensitivity (ratio of sensitivity at certain  $H_x$  and sensitivity at  $H_x = 0.5$  kA/m).



1998 Mar 24

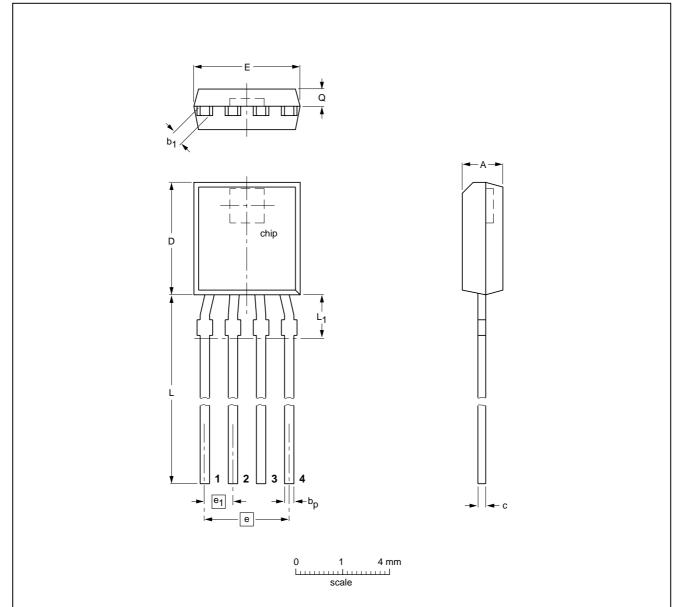
# Magnetic field sensor

KMZ10A

#### **PACKAGE OUTLINE**

Plastic single-ended flat package; 4 in-line leads

**SOT195** 



#### DIMENSIONS (mm are the original dimensions)

UNIT	Α	bp	b <sub>1</sub>	С	D	E	е	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup> max.	Q
mm	1.8 1.6	0.48 0.40	0.7 0.5	0.45 0.39	5.2 5.0	4.8 4.4	3.75	1.25	14.5 12.7	2	0.8 0.7

#### Notes

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT195				$ \  \   \bigoplus  \big($	97-06-02

### Magnetic field sensor

KMZ10A

#### **DEFINITIONS**

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	•

#### Limiting values

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

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